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(5-2008)

# High Speed Infrared Emitting Diodes, 940 nm, GaAlAs, MQW



#### **DESCRIPTION**

VSMB2943X01 series are infrared, 940 nm emitting diodes in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

#### **APPLICATIONS**

- IrDA compatible data transmission
- · Miniature light barrier
- IR touch panels
- 3D TV
- Photointerrupters
- · Optical switch
- · Control and drive circuits
- Shaft encoders

#### **FEATURES**

Package type: surface mount

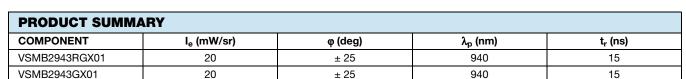
Package form: GW, RGW



AEC-Q101 qualified

Peak wavelength: λ<sub>p</sub> = 940 nm

- High reliability
- · High radiant power
- High radiant intensity
- Angle of half intensity:  $\varphi = \pm 25^{\circ}$
- · Low forward voltage
- · Suitable for high pulse current operation
- Terminal configurations: gullwing or reserve gullwing
- Package matches with detector VEMD2xx3X01 and VEMT2xx3X01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>



#### Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMB2943RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMB2943GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

#### Note

• MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		$V_{R}$	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	А	
Power dissipation		P <sub>V</sub>	160	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C	
Soldering temperature	according figure 9, J-STD-020	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R <sub>thJA</sub>	250	K/W	

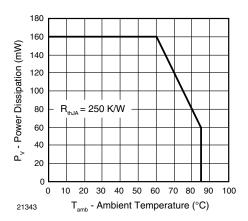


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

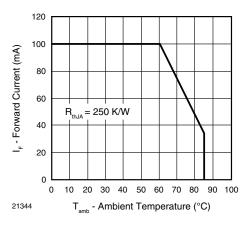


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Farmer veltare	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>	1.15	1.35	1.6	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	$V_{F}$		2.2		V
Temperature coefficient of V	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		-1.8		mV/K
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>		-1.1		mV/K
Reverse current		I <sub>R</sub>	Not design	Not designed for reverse operation		
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ		70		pF
Dedicat intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	10	20	30	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	I <sub>e</sub>		170		V mV/K mV/K  µA pF mW/sr mW/sr mW/sr mW %/K %/K deg nm nm/K
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		40		mW
Temperature coefficient of radiant	I <sub>F</sub> = 1 mA	TKφ <sub>e</sub>		-1.1	operation         μA           pF         30           30         mW/sr           mW/sr         mW           %/K         %/K           deg         960           nm         nm	
power	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>		-0.51		%/K
Angle of half intensity		φ		± 25		deg
Peak wavelength	I <sub>F</sub> = 30 mA	$\lambda_{p}$	920	940	960	nm
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ		25		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 30 mA	TKλ <sub>p</sub>		0.25		nm/K
Rise time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>r</sub>		15		ns
Fall time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>f</sub>		15		ns
Cut-off frequency	I <sub>DC</sub> = 70 mA, I <sub>AC</sub> = 30 mA pp	f <sub>c</sub>		23		MHz

### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

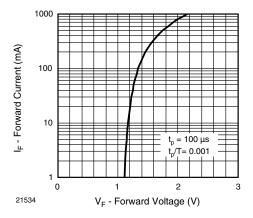


Fig. 3 - Forward Current vs. Forward Voltage

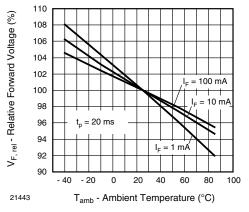


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

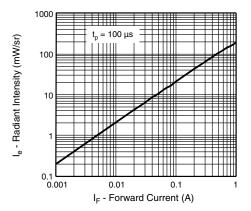


Fig. 5 - Radiant Intensity vs. Forward Current

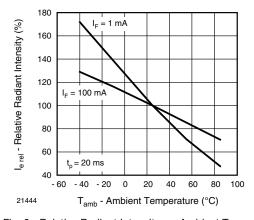


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

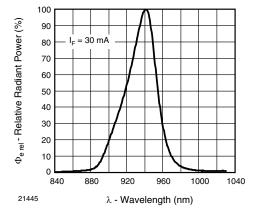


Fig. 7 - Relative Radiant Power vs. Wavelength

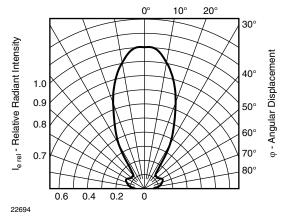


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

#### **SOLDER PROFILE**

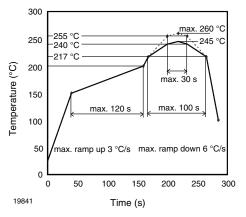


Fig. 9 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

#### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

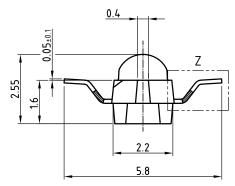
Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

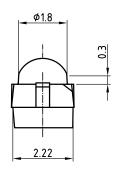
Moisture sensitivity level 2a, acc. to J-STD-020.

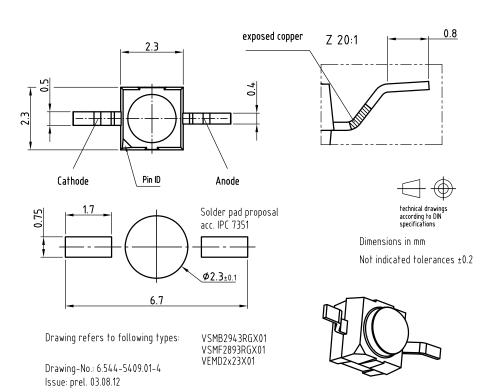
#### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40  $^{\circ}$ C (+ 5  $^{\circ}$ C), RH < 5  $^{\circ}$ M.

#### PACKAGE DIMENSIONS in millimeters: VSMB2943RG





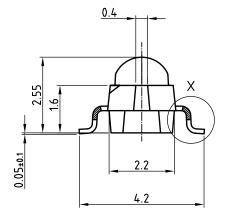


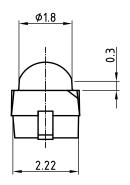


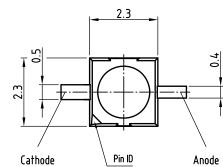
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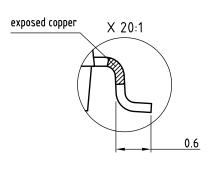
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#### PACKAGE DIMENSIONS in millimeters: VSMB2943G

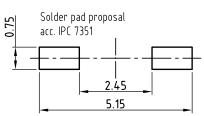










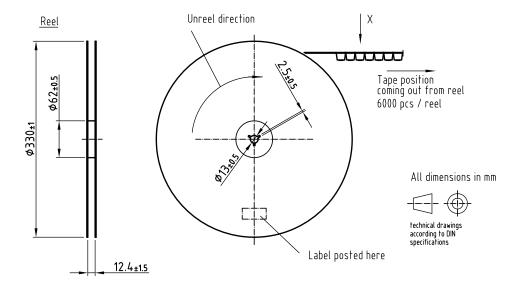


Not indicated tolerances ±0.2

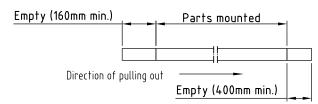
Drawing refers to following types: VSMB2943GX01 VSMF2893GX01 VEMD2x23X01

Drawing-No.: 6.544-5408.01-4 Issue: prel; 03.08.12

#### TAPING AND REEL DIMENSIONS in millimeters: VSMB2943RG

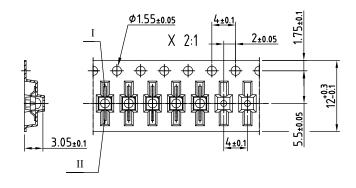


#### Leader and trailer tape:



#### Terminal position in tape

Device	Lead I	Lead II
VSMB2943RGX01		
VSMF2893RGX01	<del>-</del>	
VEMD2x03X01	carnoue	Alloue
VEMT2x03X01	Collector	Emitter
	CONSCION	riiirrei
VSMY2853RG	Anode	Cathode

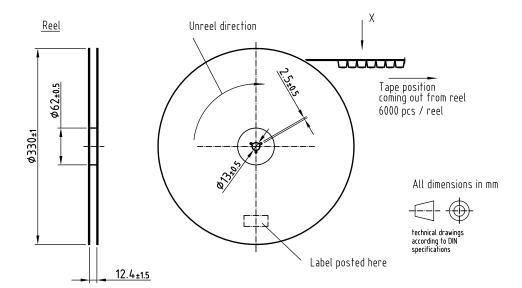


Drawing refers to following types: Reel dimensions and tape

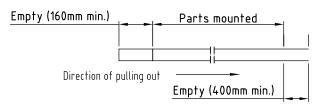
see table

Drawing-No.: 9.800-5100.02-4 Issue: prel; 03.08.12

#### TAPING AND REEL DIMENSIONS in millimeters: VSMB2943G



Leader and trailer tape:



<u>Terminal p</u>	osition in t	tape		т	Ø1.55	5±0.05	<u>4+0.1</u>	.75±0.1						
Device	Lead I	Lead II			. /	X 2:1	2±0.	.05						
VSMB2943GX01				. '	\			<b>,</b>						
VSMF2893GX01	Cathode	Anode			Φ Φ	Ф Ф	<del>•</del> • -							
VEMD2x23X01	Carnode	Alloue		ľ		ΨΨ	4	†						
									le le				1 :	12 to 2
							1 MI II A II II A III		5					
VEMT2x23X01	Collector	Emitter	2	П				±0.05						
	Cottector		-	_	1		<del> , </del>	— Ğ∥ —						
VSMY2853G	Anode	Cathode	-   - 3	.05±0.1	1		4±0 <u>.1</u>	ᅜ						
				II	1									

Drawing refers to following types: see table Reel dimensions and tape

Drawing-No.: 9.800-5091.21-4 Issue: prel; 03.08.12



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